# imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

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MPS2222A is a Preferred Device

### **General Purpose Transistors**

#### **NPN Silicon**

#### Features

• Pb-Free Packages are Available\*

#### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Collector – Emitter Voltage MPS2222 MPS2222A	V <sub>CEO</sub>	30 40	Vdc
Collector – Base Voltage MPS2222 MPS2222A	V <sub>CBO</sub>	60 75	Vdc
Emitter – Base Voltage MPS2222 MPS2222A	V <sub>EBO</sub>	5.0 6.0	Vdc
Collector Current – Continuous	Ι <sub>C</sub>	600	mAdc
Total Device Dissipation @ T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	625 5.0	mW mW/°C
Total Device Dissipation @ T <sub>C</sub> = 25°C Derate above 25°C	P <sub>D</sub>	1.5 12	W mW/°C
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

#### THERMAL CHARACTERISTICS

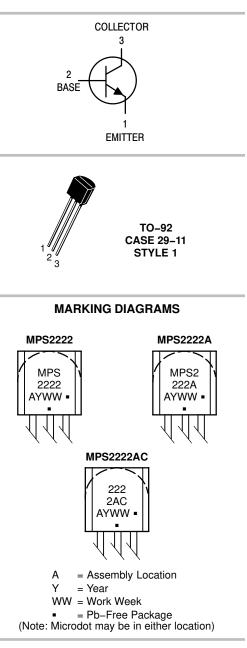
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	200	°C/W
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	83.3	°C/W

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.



#### **ON Semiconductor®**

#### http://onsemi.com



#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 6 of this data sheet.

\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

Preferred devices are recommended choices for future use and best overall value.

#### ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERISTICS					
Collector – Emitter Breakdown Voltage $(I_C = 10 \text{ mAdc}, I_B = 0)$	MPS2222 MPS2222A	V <sub>(BR)CEO</sub>	30 40		Vdc
Collector – Base Breakdown Voltage $(I_C = 10 \ \mu Adc, I_E = 0)$	MPS2222 MPS2222A	V <sub>(BR)CBO</sub>	60 75		Vdc
Emitter – Base Breakdown Voltage $(I_E = 10 \ \mu Adc, I_C = 0)$	MPS2222 MPS2222A	V <sub>(BR)EBO</sub>	5.0 6.0		Vdc
Collector Cutoff Current (V <sub>CE</sub> = 60 Vdc, V <sub>EB(off)</sub> = 3.0 Vdc)	MPS2222A	ICEX	-	10	nAdc
	MPS2222 MPS2222A MPS2222 MPS2222A	I <sub>CBO</sub>	- - - -	0.01 0.01 10 10	μAdc
Emitter Cutoff Current ( $V_{EB}$ = 3.0 Vdc, $I_{C}$ = 0)	MPS2222A	I <sub>EBO</sub>	-	100	nAdc
Base Cutoff Current ( $V_{CE}$ = 60 Vdc, $V_{EB(off)}$ = 3.0 Vdc)	MPS2222A	I <sub>BL</sub>	-	20	nAdc
ON CHARACTERISTICS					
$ \begin{array}{l} \text{DC Current Gain} \\ (I_C = 0.1 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}) \\ (I_C = 1.0 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}) \\ (I_C = 10 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}) \\ (I_C = 10 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}, T_A = -55^\circ\text{C}) \\ (I_C = 150 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}) (\text{Note 1}) \\ (I_C = 150 \text{ mAdc}, V_{CE} = 1.0 \text{ Vdc}) (\text{Note 1}) \\ (I_C = 500 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}) (\text{Note 1}) \end{array} $	MPS2222A only MPS2222 MPS2222A	h <sub>FE</sub>	35 50 75 35 100 50 30 40	- - 300 - -	_
Collector – Emitter Saturation Voltage (Note 1) ( $I_C = 150$ mAdc, $I_B = 15$ mAdc) ( $I_C = 500$ mAdc, $I_B = 50$ mAdc)	MPS2222 MPS2222A MPS2222 MPS2222A	V <sub>CE(sat)</sub>	- - - -	0.4 0.3 1.6 1.0	Vdc
Base – Emitter Saturation Voltage (Note 1) ( $I_C = 150$ mAdc, $I_B = 15$ mAdc) ( $I_C = 500$ mAdc, $I_B = 50$ mAdc)	MPS2222 MPS2222A MPS2222 MPS2222A	V <sub>BE(sat)</sub>	_ 0.6 _	1.3 1.2 2.6 2.0	Vdc
SMALL-SIGNAL CHARACTERISTICS					
Current-Gain – Bandwidth Product (Note 2) ( $I_C = 20$ mAdc, $V_{CE} = 20$ Vdc, f = 100 MHz)	MPS2222 MPS2222A	f <sub>T</sub>	250 300		MHz
Output Capacitance ( $V_{CB}$ = 10 Vdc, $I_E$ = 0, f = 1.0 MHz)		C <sub>obo</sub>	-	8.0	pF
Input Capacitance $(V_{EB} = 0.5 \text{ Vdc}, I_C = 0, f = 1.0 \text{ MHz})$	MPS2222 MPS2222A	C <sub>ibo</sub>		30 25	pF
Input Impedance ( $I_C = 1.0 \text{ mAdc}$ , $V_{CE} = 10 \text{ Vdc}$ , f = 1.0 kHz) ( $I_C = 10 \text{ mAdc}$ , $V_{CE} = 10 \text{ Vdc}$ , f = 1.0 kHz)	MPS2222A MPS2222A	h <sub>ie</sub>	2.0 0.25	8.0 1.25	kΩ
Voltage Feedback Ratio ( $I_C = 1.0 \text{ mAdc}$ , $V_{CE} = 10 \text{ Vdc}$ , $f = 1.0 \text{ kHz}$ ) ( $I_C = 10 \text{ mAdc}$ , $V_{CE} = 10 \text{ Vdc}$ , $f = 1.0 \text{ kHz}$ )	MPS2222A MPS2222A	h <sub>re</sub>		8.0 4.0	X 10 <sup>-4</sup>
$      Small-Signal Current Gain \\ (I_C = 1.0 mAdc, V_{CE} = 10 Vdc, f = 1.0 kHz) \\ (I_C = 10 mAdc, V_{CE} = 10 Vdc, f = 1.0 kHz) $	MPS2222A MPS2222A	h <sub>fe</sub>	50 75	300 375	-
Output Admittance ( $I_C = 1.0 \text{ mAdc}$ , $V_{CE} = 10 \text{ Vdc}$ , $f = 1.0 \text{ kHz}$ ) ( $I_C = 10 \text{ mAdc}$ , $V_{CE} = 10 \text{ Vdc}$ , $f = 1.0 \text{ kHz}$ )	MPS2222A MPS2222A	h <sub>oe</sub>	5.0 25	35 200	μmhos
Collector Base Time Constant ( $I_E = 20 \text{ mAdc}, V_{CB} = 20 \text{ Vdc}, f = 31.8 \text{ MHz}$ )	MPS2222A	rb'C <sub>c</sub>	-	150	ps
Noise Figure (I <sub>C</sub> = 100 $\mu$ Adc, V <sub>CE</sub> = 10 Vdc, R <sub>S</sub> = 1.0 kΩ, f = 1.0 kHz)	MPS2222A	NF	-	4.0	dB

1. Pulse Test: Pulse Width  $\leq$  300 µs, Duty Cycle  $\leq$  2%. 2. f<sub>T</sub> is defined as the frequency at which  $|h_{fe}|$  extrapolates to unity.

ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ$	C unless otherwise noted) (Continued)				
Characterist	tic	Symbol	Min	Max	Unit
SWITCHING CHARACTERISTICS MPS222	2A only				
Delay Time (V <sub>C</sub>	$_{\rm CC}$ = 30 Vdc, V <sub>BE(off)</sub> = -0.5 Vdc,	t <sub>d</sub>	-	10	ns
Rise Time	= 150 mAdc, I <sub>B1</sub> = 15 mAdc) (Figure 1)	t <sub>r</sub>	-	25	ns
Storage Time (V <sub>C</sub>	<sub>CC</sub> = 30 Vdc, I <sub>C</sub> = 150 mAdc,	ts	-	225	ns
Fall Time	$= I_{B2} = 15 \text{ mAdc}$ (Figure 2)	t <sub>f</sub>	-	60	ns

#### **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted) (Continued)

#### SWITCHING TIME EQUIVALENT TEST CIRCUITS

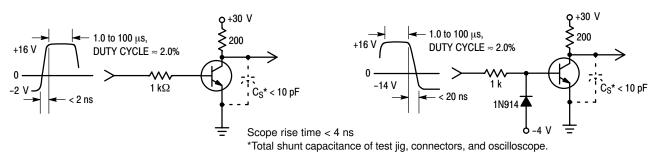
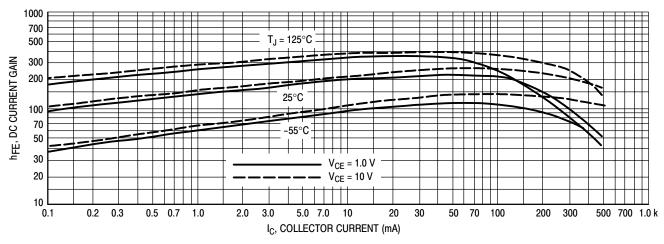
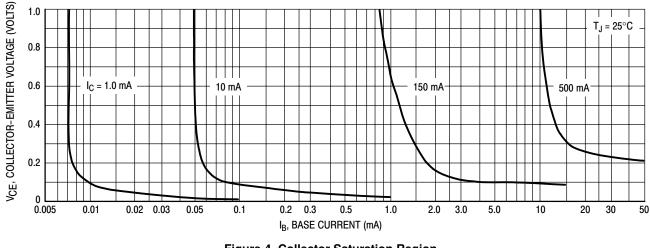


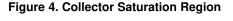


Figure 2. Turn–Off Time









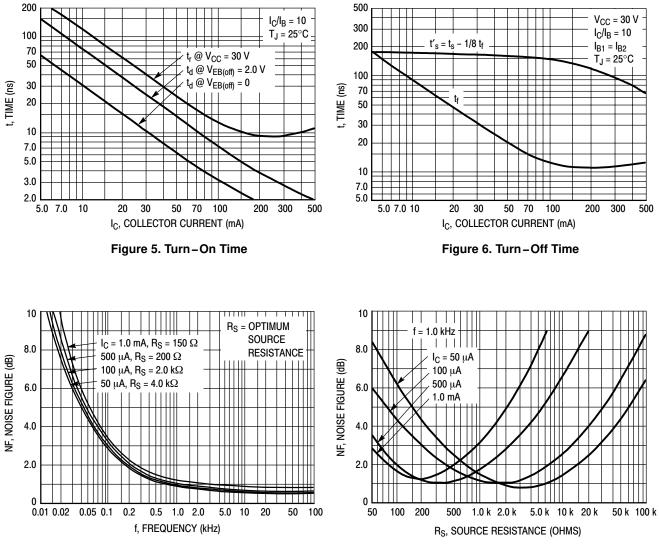


Figure 7. Frequency Effects



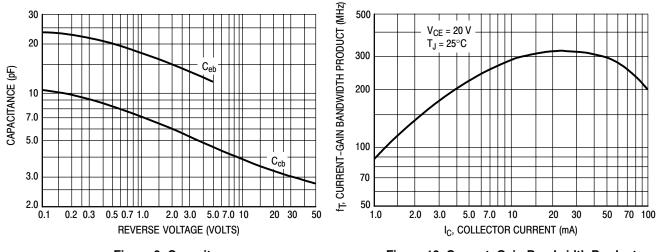


Figure 9. Capacitances

Figure 10. Current–Gain Bandwidth Product

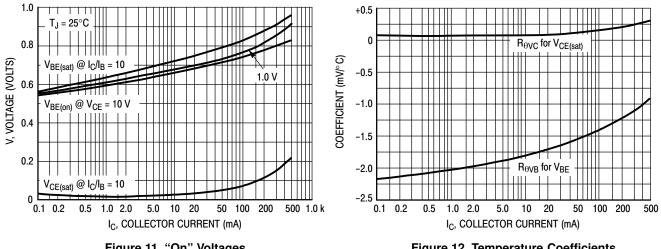


Figure 11. "On" Voltages

Figure 12. Temperature Coefficients

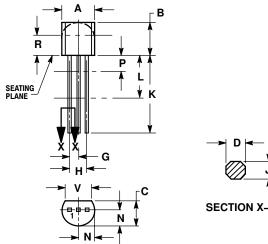
#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
MPS2222	TO-92	5000 Units / Bulk
MPS2222G	TO–92 (Pb–Free)	5000 Units / Bulk
MPS2222RLRA	TO-92	2000 / Tape & Reel
MPS2222RLRAG	TO–92 (Pb–Free)	2000 / Tape & Reel
MPS2222RLRM	TO-92	2000 / Tape & Ammo Box
MPS2222RLRMG	TO-92 (Pb-Free)	2000 / Tape & Ammo Box
MPS2222RLRP	TO-92	2000 / Tape & Ammo Box
MPS2222RLRPG	TO-92 (Pb-Free)	2000 / Tape & Ammo Box
MPS2222A	TO-92	5000 Units / Bulk
MPS2222AG	TO-92 (Pb-Free)	5000 Units / Bulk
MPS2222ARL	TO-92	2000 / Tape & Reel
MPS2222ARLG	TO–92 (Pb–Free)	2000 / Tape & Reel
MPS2222ARLRA	TO-92	2000 / Tape & Reel
MPS2222ARLRAG	TO-92 (Pb-Free)	2000 / Tape & Reel
MPS2222ARLRM	TO-92	2000 / Tape & Reel
MPS2222ARLRMG	TO–92 (Pb–Free)	2000 / Tape & Reel
MPS2222ARLRP	TO-92	2000 / Tape & Ammo Box
MPS2222ARLRPG	TO-92 (Pb-Free)	2000 / Tape & Ammo Box
MPS2222AZL1	TO-92	2000 / Tape & Ammo Box
MPS2222AZL1G	TO-92 (Pb-Free)	2000 / Tape & Ammo Box
MPS2222ACRLRP	TO-92	2000 / Tape & Ammo Box
MPS2222ACRLRPG	TO–92 (Pb–Free)	2000 / Tape & Ammo Box

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

#### PACKAGE DIMENSIONS

TO-92 (TO-226) CASE 29-11 ISSUE AL







NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI 1. Y14.5M, 1982.
- 2
- TIA-3M, 1962. CONTROLLING DIMENSION: INCH. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED. LEAD DIMENSION IS UNCONTROLLED IN P AND 3.
- 4. BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.20
В	0.170	0.210	4.32	5.33
С	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
Κ	0.500		12.70	
L	0.250		6.35	
Ν	0.080	0.105	2.04	2.66
Р		0.100		2.54
R	0.115		2.93	
٧	0.135		3.43	

STYLE 1: PIN 1. EMITTER

BASE 2. 3.

COLLECTOR

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